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<u>, 24小时加急出货</u> TPS71319 TPS71334

SBVS055A-DECEMBER 2004-REVISED JANUARY 2005

# Dual 250 mA Output, UltraLow Noise, High PSRR, Low-Dropout Linear Regulator with Integrated SVS

# FEATURES

EXAS

NSTRUMENTS

- Dual 250 mA High-Performance RF LDOs
- Integrated Supply Voltage Supervisor Monitors V<sub>OUT2</sub>
- Available in Fixed and Adjustable Voltage Options (1.2 V to 5.5 V)
- High PSRR: 65 dB at 10 kHz
- UltraLow Noise: 32 µVrms
- Fast Start-Up Time: 60 µs
- Stable with 2.2 µF Ceramic Capacitor
- Excellent Load/Line Transient Response
- Very Low Dropout Voltage: 125 mV at 250 mA
- Independent Enable Pins
- Thermal Shutdown and Independent Current
  Limit
- Available in Thermally-Enhanced SON
   Package: 3mm x 3mm x 1mm

## **APPLICATIONS**

- Cellular and Cordless Phones
- Wireless PDA/Handheld Products
- PCMCIA/Wireless LAN Applications
- Digital Camera/Camcorder/Internet Audio
- DSP/FPGA/ASIC/Controllers and Processors



# DESCRIPTION

The TPS713xx family of low-dropout (LDO) voltage regulators is tailored to noise-sensitive and RF applications. These products feature dual 250 mA LDOs with ultralow noise, high power-supply rejection ratio (PSRR), and fast transient and start-up response. These devices also feature an integrated supply voltage supervisor (SVS) that monitors the voltage at OUT2 and will assert if the voltage falls to 95% (typical) of the measured output. Each regulator output is stable with low-cost 2.2 µF ceramic output capacitors and features very low dropout voltages (125 mV typical at 250 mA). Each regulator achieves fast start-up times (approximately 60 µs with a 0.001 µF bypass capacitor) while consuming very low quiescent current (300 µA typical with both outputs enabled). When the device is placed in standby mode, the supply current is reduced to less than 0.3 µA typical. Each regulator exhibits approximately 32  $\mu$ Vrms of output voltage noise with V<sub>OUT</sub> = 2.8 V and a 0.01 µF noise reduction (NR) capacitor. Appliwith analog components that cations are noise-sensitive, such as portable RF electronics, will benefit from high PSRR, low noise, and fast line and load transient features. The TPS713xx family is offered in a thin 3mm x 3mm SON package and is fully specified from -40°C to +125°C (T<sub>J</sub>).



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **ORDERING INFORMATION**<sup>(1)</sup>

|          | VOLTA             | GE (T <sub>J</sub> ) | PACKAGE-             |  |                    |                    |                              |  |
|----------|-------------------|----------------------|----------------------|--|--------------------|--------------------|------------------------------|--|
| PRODUCT  | V <sub>OUT1</sub> | V <sub>OUT2</sub>    | LEAD<br>(DESIGNATOR) | TEMPERATURE<br>RANGE (T <sub>J</sub> ) | PACKAGE<br>MARKING | ORDERING<br>NUMBER | TRANSPORT<br>MEDIA, QUANTITY |  |
| TPS71319 | 1.8 V             | Adiustable           | SON-10 (DRC)         | -40°C to +125°C                        | ARP                | TPS71319DRCT       | Tape and Reel, 250           |  |
| 1571319  | 1.0 V             | Aujustable           | 3011-10 (DRC)        | -40 C 10 +125 C                        | ANE                | TPS71319DRCR       | Tape and Reel, 3000          |  |
| TPS71334 | 3.3 V             | Adiustable           |                      | -40°C to +125°C                        | ARO                | TPS71334DRCT       | Tape and Reel, 250           |  |
| 153/1334 | 3.3 V             | Aujustable           | SON-10 (DRC)         | -40 C 10 +125 C                        | AKU                | TPS71334DRCR       | Tape and Reel, 3000          |  |

(1) For the most current package and ordering information, see the Package Ordering Addendum located at the end of this data sheet.

#### **ABSOLUTE MAXIMUM RATINGS**

over operating junction temperature range unless otherwise noted<sup>(1)</sup>

|  | TPS713xx                      | UNIT                          |  |  |
|--|-------------------------------|-------------------------------|--|--|
| V <sub>IN</sub> range                      | -0.3 to 6.0                   | V                             |  |  |
| V <sub>RESET</sub> range                   | -0.3 to V <sub>IN</sub> + 0.3 | V                             |  |  |
| V <sub>EN1</sub> , V <sub>EN2</sub> range  | -0.3 to V <sub>IN</sub> + 0.3 | V                             |  |  |
| V <sub>OUT</sub> range                     | -0.3 to 6.0                   | V                             |  |  |
| Peak output current                        | Internally limited            |                               |  |  |
| Output short-circuit duration              | Indefinite                    |                               |  |  |
| Continuous total power dissipation         | See Dissipation Ratings T     | See Dissipation Ratings Table |  |  |
| Junction temperature range, T <sub>J</sub> | -40 to +150                   | °C                            |  |  |
| Storage temperature range                  | -65 to +150                   | °C                            |  |  |
| ESD rating, HBM                            | 2                             | kV                            |  |  |
| ESD rating, CDM                            | 500                           | V                             |  |  |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under the Electrical Characteristics is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

### POWER DISSIPATION RATINGS

| BOARD                 | PACKAGE | $R_{	extsf{	heta}JC}$ | $R_{\theta JA}$ | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> ≤ 25°C<br>POWER RATING | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING |
|-----------------------|---------|-----------------------|-----------------|--|---------------------------------------|---------------------------------------|---------------------------------------|
| High-K <sup>(1)</sup> | DRC     | 48                    | 52              | 19 mW/°C                                       | 1.92 W                                | 1.06 W                                | 0.77 W                                |

(1) The JEDEC High-K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1-ounce internal power and ground planes and 2-ounce copper traces on the top and bottom of the board.

#### **ELECTRICAL CHARACTERISTICS**

Over operating temperature range (T<sub>J</sub> = -40°C to +125°C), V<sub>IN</sub> = highest V<sub>OUT(nom)</sub> + 1.0 V or 2.7 V (whichever is greater), I<sub>OUT</sub> = 1 mA, V<sub>EN1, 2</sub> = 1.2 V, C<sub>OUT</sub> = 10  $\mu$ F, C<sub>NR</sub> = 0.01  $\mu$ F, and adjustable LDOs are tested at V<sub>OUT</sub> = 3.0 V, unless otherwise noted. Typical values are at T<sub>J</sub> = 25°C.

|                                   | PARAMETER  |   | TEST CONDITIONS  | MIN                   | TYP   | MAX             | UNIT              |  |
|-----------------------------------|--|---|--|-----------------------|---|-----------------|-------------------|--|
| V <sub>IN</sub>                   | Input voltage range <sup>(1)</sup>                                   |   |  | 2.7                   |   | 5.5             | V                 |  |
| V <sub>FB</sub>                   | Internal reference (adjust   | able LDOs)  |  | 1.200                 | 1.225   | 1.250           | V                 |  |
|                                   | Output voltage range (adjustable LDOs)                               |   |  | $V_{FB}$              | VFB         5.5 - VDO           -1.5         +1.5           -3         ±1         +3           0.05         0.8         125           125         230         400         600         800 |                 |                   |  |
| V <sub>OUT</sub>                  |  | Nominal   | $T_J = 25^{\circ}C, I_{OUT} = 0 \text{ mA}$  | -1.5                  |   | +1.5            |                   |  |
|                                   | Accuracy <sup>(1)</sup>  | $\begin{array}{l} \text{Over V}_{\text{IN}}, \\ \text{I}_{\text{OUT}}, \text{ and T} \end{array}$ | $ \begin{array}{l} V_{OUT} + 1.0 \ V \leq V_{IN} \leq 5.5 \ V, \\ 0 \ \mu A \leq I_{OUT} \leq 250 \ mA \end{array} $ | -3                    | ±1  | +3              | %                 |  |
| $\Delta V_{OUT}\%/\Delta V_{IN}$  | Line regulation <sup>(1)</sup>                                       |   | $V_{OUT} + 1.0 \text{ V} \leq V_{IN} \leq 5.5 \text{ V}$   |                       | 0.05  |                 | %/V               |  |
| $\Delta V_{OUT}\%/\Delta I_{OUT}$ | Load regulation  |   | $0 \ \mu A \leq I_{OUT} \leq 250 \ mA$   |                       | 0.8   |                 | %/mA              |  |
| V <sub>DO</sub>                   | Dropout voltage <sup>(2)</sup><br>( $V_{IN} = V_{OUT(nom)} - 0.1V$ ) | 2.8 V,<br>2.85 V<br>Adjustable  | $I_{OUT1} = I_{OUT2} = 250 \text{ mA}$   |                       | 125   | 230             | mV                |  |
| I <sub>CL</sub>                   | Output current limit   |   | $V_{OUT} = 0.9 \times V_{OUT(nom)}$  | 400                   | 600   | 800             | mA                |  |
|                                   | Cround his ourrent   | One LDO<br>enabled  | I <sub>OUT</sub> = 1 mA (enabled channel)  |                       | 190   | 250             |                   |  |
| I <sub>GND</sub>                  | Ground pin current   | Both LDOs enabled   | $I_{OUT1} = I_{OUT2} = 1 \text{ mA to } 250 \text{ mA}$  |                       | 300   | 600             | μA                |  |
| I <sub>SHDN</sub>                 | Shutdown current <sup>(3)</sup>                                      |   | $\frac{V_{EN} \leq 0.4}{RESET}$ open   |                       | 0.3   | 2.0             | μA                |  |
| I <sub>FB</sub>                   | FB pin current (adjustable   | e LDOs)   |  |                       | 0.1   | 1               | μA                |  |
| V <sub>n</sub>                    | Output noise voltage,  |   | No $C_{NR}$ , $I_{OUT}$ = 250 mA   | 80.0                  | $0 \times V_{OUT}$  |                 | µVrms             |  |
| ۷n                                | BW = 10 Hz - 100 kHz   |   | $C_{NR} = 0.01 \ \mu F, \ I_{OUT} = 250 \ mA$  | $11.8 \times V_{OUT}$ |   |                 | μο                |  |
| PSRR                              | Power-supply rejection ra  | tio   | f = 100 Hz, I <sub>OUT</sub> = 250 mA  | 65                    |   | dB              |                   |  |
|                                   | (ripple rejection)   |   | f = 10 kHz, I <sub>OUT</sub> = 250 mA  |                       | 65  |                 | db                |  |
| t <sub>STR</sub>                  | Startup time   |   | $V_{OUT}$ = 2.85 V, $R_L$ = 30 $\Omega$ , $C_{NR}$ = 0.001 $\mu$ F   |                       | 60  |                 | μs                |  |
| V <sub>IH</sub>                   | Enable threshold high (El  | N1, EN2)  |  | 1.2                   |   | $V_{\text{IN}}$ | V                 |  |
| V <sub>IL</sub>                   | Enable threshold low (EN   | 1, EN2)   |  | 0                     |   | 0.4             | V                 |  |
| I <sub>EN</sub>                   | Enable pin current (EN1,   |   | $V_{IN} = V_{EN} = 5.5 V$  | -1                    |   | 1               | μA                |  |
|                                   | Minimum V <sub>IN</sub> for valid RE                                 | SET   | I <sub>RESET</sub> = 10 μA   |                       | 0.6   |                 | V                 |  |
| V <sub>RESET, LO</sub>            | RESET output low voltag  | e   | I <sub>RESET</sub> = 1 mA  |                       |   | 0.4             | V                 |  |
| I <sub>LKG, RESET</sub>           | RESET leakage current  |   | $V_{IN} = V_{RESET} = 5.5 V$   |                       | 10  | 500             | nA                |  |
| V <sub>IT</sub>                   | RESET threshold voltage  |   | V <sub>OUT2</sub> falling <sup>(4)</sup>   | 92.5                  |   | 97.5            | %V <sub>OUT</sub> |  |
| V <sub>HYS</sub>                  | RESET threshold hystere  | sis   | V <sub>OUT2</sub> rising <sup>(4)</sup>  |                       | 0.5   |                 | %V <sub>OUT</sub> |  |
| T <sub>D</sub>                    | RESET delay time   |   |  | 50                    | 100   | 200             | ms                |  |
| T <sub>P</sub>                    | RESET propagation delay  | /   |  |                       | 10  |                 | μs                |  |
| T <sub>SD</sub>                   | Thermal shutdown temperature   |   | Shutdown         Temp increasing           Reset         Temp decreasing   |                       | +160<br>+140  |                 | °C                |  |
| 111/1 0                           | Under-voltage lockout thr  | eshold  | V <sub>IN</sub> rising   | 2.25                  |   | 2.65            | V                 |  |
| UVLO                              | Under-voltage lockout hys  | steresis  | V <sub>IN</sub> falling  |                       | 100   |                 | mV                |  |

(1) Minimum  $V_{IN} = V_{OUT} + V_{DO}$  or 2.7 V, whichever is greater. (2)  $V_{DO}$  is not measured for 1.8 V regulators since minimum  $V_{IN} = 2.7$  V. (3) For the adjustable version, this applies only after  $V_{IN}$  is applied; then  $V_{EN}$  transitions from high to low. (4) RESET threshold and hysteresis is a percentage of the measured output.



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#### Table 1. TERMINAL FUNCTIONS

| TERM   | IINAL  | DESCRIPTION   |
|--------|--------|---|
| NAME   | DRC    | DESCRIPTION   |
| IN     | 1      | Unregulated input supply. A 0.1 µF capacitor should be connected from IN to GND.  |
| GND    | 5, Pad | Ground  |
| OUT1   | 3      | Output of the regulator. A small 2.2 $\mu F$ ceramic capacitor is required from this pin to ground to assure stability.   |
| OUT2   | 4      | Same as OUT1 but for LDO2.  |
| EN1    | 10     | Driving the enable pin (EN) high turns on LDO1. Driving this pin low puts LDO1 into shutdown mode, reducing operating current. The enable pin should be connected to IN if not used.                        |
| EN2    | 8      | Same as EN1 but controls LDO2.  |
| NC     | 9      | No connection.  |
| FB2/NC | 7      | Feedback for CH2 adjustable version; no connection for non-adjustable CH2.  |
| NR     | 6      | Noise reduction pin; connect an external bypass capacitor to reduce LDO output noise.   |
| RESET  | 2      | Open-drain reset output; monitors OUT2. A 10 k $\Omega$ to 1 M $\Omega$ pull-up resistor is suitable for most applications. The open-drain RESET pull-up voltage should not exceed V <sub>DD</sub> + 0.3 V. |



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#### **TYPICAL CHARACTERISTICS**

For all voltage versions at  $T_J = 25^{\circ}C$ ,  $V_{IN} = V_{OUT(nom)} + 1$  V,  $I_{OUT} = 1$  mA,  $V_{EN} = 1.2$  V,  $C_{OUT} = 2.2$  µF, and  $C_{NR} = 0.01$  µF, unless otherwise noted.





# OUTPUT VOLTAGE vs TEMPERATURE









DROPOUT VOLTAGE vs INPUT VOLTAGE (ADJUSTABLE OUTPUTS)





#### DROPOUT VOLTAGE vs JUNCTION TEMPERATURE







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#### **TYPICAL CHARACTERISTICS (continued)**

For all voltage versions at  $T_J = 25^{\circ}C$ ,  $V_{IN} = V_{OUT(nom)} + 1$  V,  $I_{OUT} = 1$  mA,  $V_{EN} = 1.2$  V,  $C_{OUT} = 2.2$  µF, and  $C_{NR} = 0.01$  µF, unless otherwise noted.





**GROUND PIN CURRENT vs JUNCTION TEMPERATURE** 



Figure 9.







GROUND PIN CURRENT vs JUNCTION TEMPERATURE (DISABLED)





#### TPS71334 LINE TRANSIENT RESPONSE



Figure 12.



#### **TYPICAL CHARACTERISTICS (continued)**

For all voltage versions at  $T_J = 25^{\circ}C$ ,  $V_{IN} = V_{OUT(nom)} + 1$  V,  $I_{OUT} = 1$  mA,  $V_{EN} = 1.2$  V,  $C_{OUT} = 2.2$  µF, and  $C_{NR} = 0.01$  µF, unless otherwise noted.



Figure 13.



















80

70

60

50

40

30

20

10

0

10

V<sub>OUT</sub> = 2.8 V (adj)

100

1k

C<sub>OUT</sub> = 2.2 μF

 $C_{NR} = 0.01 \ \mu F$ 

PSRR (dB)



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#### **TYPICAL CHARACTERISTICS (continued)**

For all voltage versions at  $T_J = 25^{\circ}C$ ,  $V_{IN} = V_{OUT(nom)} + 1$  V,  $I_{OUT} = 1$  mA,  $V_{EN} = 1.2$  V,  $C_{OUT} = 2.2$  µF, and  $C_{NR} = 0.01$  µF, unless otherwise noted.



Figure 19.

**PSRR (RIPPLE REJECTION) vs FREQUENCY** 

 $I_{OUT} = 1 \text{ mÅ}$ 

10k

Frequency (Hz)

Figure 21.

= 250 mA

I<sub>OUT</sub>

100k

1M

10M



Figure 20.













#### **APPLICATION INFORMATION**

The TPS713xx family of dual low-dropout (LDO) regulators has been optimized for use in noise-sensitive battery-operated equipment. The device features extremely low dropout, high PSRR, ultralow output noise, and low quiescent current (190  $\mu$ A typically per channel). When both outputs are disabled, the supply currents are reduced to less than 2 $\mu$ A. A typical application circuit with sequencing is shown in Figure 24.



Figure 24. Typical Application Circuit (with output sequencing)

# INPUT AND OUTPUT CAPACITOR REQUIREMENTS

A 0.1  $\mu$ F or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS713xx, is required for stability. It improves transient response, noise rejection, and ripple rejection. A higher-value input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

The TPS713xx requires an output capacitor connected between the outputs and GND to stabilize the internal control loops. The minimum recommended output capacitor is 2.2  $\mu$ F. If an output voltage of

1.8 V or less is chosen, the minimum recommended output capacitor is 4.7  $\mu$ F. Any ceramic capacitor that meets the minimum output capacitor requirements is suitable. Capacitors with higher ESR may be used, provided the worst-case ESR is less than 1 $\Omega$ .

### **OUTPUT NOISE**

The internal voltage reference is a key source of noise in an LDO regulator. The TPS713xx has an NR pin that is connected to the voltage reference through a 250 k $\Omega$  internal resistor. The 250 k $\Omega$  internal resistor, in conjunction with an external ceramic bypass capacitor connected to the NR pin, creates a low-pass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. To achieve a fast startup, the 250 k $\Omega$  internal resistor is shorted for 400 µs after the device is enabled.

Because the primary noise source is the internal voltage reference, the output noise will be greater for higher output voltage versions. For the case where no noise reduction capacitor is used, the typical noise ( $\mu$ Vrms) over 10 Hz to 100 kHz is 30 times the output voltage. If a 0.01  $\mu$ F capacitor is used from the NR pin to ground, the noise ( $\mu$ Vrms) drops to 11.8 times the output voltage. For example, the TPS71334 with the adjustable output set to 2.8 V exhibits only 33  $\mu$ Vrms of output voltage noise using a 0.01  $\mu$ F ceramic bypass capacitor and a 2.2  $\mu$ F ceramic output capacitor.

### STARTUP CHARACTERISTICS

To minimize startup overshoot, the TPS713xx will initially target an output voltage that is approximately 80% of the final value. To avoid a delayed startup time, noise reduction capacitors of 0.01  $\mu$ F or less are recommended. Larger noise reduction capacitors will cause the output to hold at 80% until the voltage on the noise reduction capacitor exceeds 80% of the bandgap voltage. The typical startup time with a 0.001  $\mu$ F noise reduction capacitor is 60  $\mu$ s. Once one of the output voltages is present, the startup time of the other output will not be affected by the noise reduction capacitor.

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#### PROGRAMMING THE TPS71202 ADJUSTABLE LDO REGULATOR

The output voltage of the TPS71202 dual adjustable regulator is programmed using an external resistor divider, as shown in Figure 24. The output voltage is calculated using Equation 1:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right)$$
(1)

where  $V_{REF} = 1.225$  V (the internal reference voltage).

Resistors R2 and R4 should be chosen for approximately a 40  $\mu$ A divider current. Lower value resistors can be used for improved noise performance, but will consume more power. Higher values should be avoided because leakage current at FB increases the output voltage error. The recommended design procedure is to choose R2 = 30.1 k $\Omega$  to set the divider current at 40  $\mu$ A, and then calculate R1 using Equation 2:

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R2$$
(2)

To improve the stability and noise performance of the adjustable version, a small compensation capacitor can be placed between OUT and FB.

For voltages  $\leq$  1.8 V, the value of this capacitor should be 100 pF. For voltages > 1.8 V, the approximate value of this capacitor can be calculated as Equation 3:





$$C1 = \frac{(3 \times 10^{5}) \times (R1 + R2)}{(R1 \times R2)} (pF)$$
(3)

The suggested value of this capacitor for several resistor ratios is shown in Figure 25. If this capacitor is not used (such as in a unity-gain configuration) or if an output voltage  $\leq 1.8$  V is chosen, then the minimum recommended output capacitor is 4.7  $\mu$ F instead of 2.2  $\mu$ F.

#### DROPOUT VOLTAGE

The TPS713xx uses a PMOS pass transistor to achieve extremely low dropout. When (V<sub>IN</sub> - V<sub>OUT</sub>) is less than the dropout voltage ( $V_{DO}$ ), the PMOS pass device is in its linear region of operation and the input-to-output resistance is the R<sub>DS. ON</sub> of the PMOS pass element. Dropout voltages at lower currents can be approximated by calculating the effective R<sub>DS, ON</sub> of the pass element and multiplying that resistance by the load current. R<sub>DS. ON</sub> of the pass element can be obtained by dividing the dropout voltage by the rated output current. For the TPS71334, the R<sub>DS. ON</sub> of the pass element is 84 m $\Omega$ . The dropout voltage of the TPS713xx will be less for higher output voltage versions. This is because the PMOS pass element will have lower on-resistance due to increased gate drive.

**Output Voltage Programming Guide** 

| V <sub>OUT2</sub> | R1      | R2      | C1     |
|-------------------|---------|---------|--------|
| 1.225 V           | Short   | Open    | Open   |
| 1.5 V             | 7.15 kΩ | 30.1 kΩ | 100 pF |
| 2.5 V             | 31.6 kΩ | 30.1 kΩ | 22 pF  |
| 3.0 V             | 43.2 kΩ | 30.1 kΩ | 15 pF  |
| 3.3 V             | 49.9 kΩ | 30.1 kΩ | 15 pF  |
| 4.75 V            | 86.6 kΩ | 30.1 kΩ | 15 pF  |

Figure 25. TPS71334 Adjustable LDO Regulator Programming



#### SUPERVISOR DESCRIPTION

The TPS713xx has an on-chip supply voltage supervisor (SVS) that monitors the voltage at OUT2. The RESET output will assert if  $V_{OUT2}$  is below the reset threshold ( $V_{IT}$ ). When OUT2 exceeds the reset threshold plus hysteresis ( $V_{HYS}$ ), the RESET output will remain low for the specified delay time ( $t_D$ ). When OUT2 is disabled by EN2 or the input voltage is below the under-voltage lockout (UVLO), the reset signal is automatically asserted. The functionality of the reset circuit is shown in Figure 26 and Table 2.

The output accuracy or output divider resistor tolerances have minimal effect on the relative  $V_{IT}$ threshold accuracy. The reset threshold  $V_{IT}$  will scale accordingly to the actual output voltage. The RESET SBVS055A-DECEMBER 2004-REVISED JANUARY 2005

output will remain unasserted during transients shorter than the reset circuit propagation delay (T<sub>P</sub>). Even with a 2.2  $\mu$ F output capacitor, typical load transient conditions will not cause RESET to falsely assert.

The RESET pin requires an external resistor to pull the pin high during the unasserted state. A 10 k $\Omega$  to 1 M $\Omega$  resistor is suitable for most applications. If the resistance is too low, the pin may not pull low enough to be recognized as a valid logic signal. If the pull-up resistor is too large, the reset pin leakage may cause the device not to pull high enough in the unasserted state. The pull-up voltage for the RESET pin should not exceed V<sub>IN</sub> + 0.3 V; doing so will turn on internal ESD protection devices and may damage the device.



Figure 26. RESET Timing Diagram

| Table | 2. | Reset | Pin | Truth | Table |
|-------|----|-------|-----|-------|-------|
|-------|----|-------|-----|-------|-------|

| EN2              | UVLO<br>Asserted | V <sub>OUT2</sub>                   | RESET<br>Asserted |
|------------------|------------------|-------------------------------------|-------------------|
| X <sup>(1)</sup> | Yes              | X                                   | Yes               |
| Low              | Х                | X                                   | Yes               |
| High             | No               | V <sub>OUT2</sub> > V <sub>IT</sub> | No                |
| High             | No               | V <sub>OUT2</sub> < V <sub>IT</sub> | Yes               |

(1) X = don't care.

#### TRANSIENT RESPONSE

As with any regulator, increasing the size of the output capacitor will reduce over/undershoot magnitude but increase duration of the transient response. In the adjustable version, the addition of a capacitor,  $C_{FB}$ , from the output to the feedback pin will also improve stability and transient response. The transient response of the TPS713xx is enhanced with an active pull-down that engages when the output is over-voltaged. The active pull-down decreases the output recovery time when the load is removed. Figure 14 in the Typical Characteristics section shows the output transient response.

#### SHUTDOWN

Both enable pins are active high and are compatible with standard TTL-CMOS levels. The device is only completely disabled when both EN1 and EN2 are logic low. In this state, the LDO is completely off and the ground pin current drops to approximately 100 nA. With one output disabled, the ground pin current is slightly greater than half the nominal value. When shutdown capability is not required, the enable pins should be connected to the input supply.

#### INTERNAL CURRENT LIMIT

The TPS713xx internal current limit helps protect the regulator during fault conditions. During current limit, the output will source a fixed amount of current that is largely independent of the output voltage.

The TPS713xx PMOS-pass transistors have a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (that is, during power-down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting may be appropriate.

#### THERMAL PROTECTION

Thermal protection disables both outputs when the junction temperature of either channel rises to approximately +160°C, allowing the device to cool. When the junction temperature cools to approximately +140°C, the output circuitry is again enabled.



Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This limits the dissipation of the regulator, protecting it from damage due to overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to +125°C maximum. To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection should trigger at least +35°C above the maximum expected ambient condition of your application. This produces a worst-case junction temperature of +125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS713xx was designed to protect against overload conditions. It was not intended to replace proper heatsinking. Continuously running the TPS713xx into thermal shutdown will degrade device reliability.

#### POWER DISSIPATION

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for a JEDEC high-K board is shown in the Dissipation Ratings table. Using heavier copper will increase the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers will also improve the heat-sink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation is equal to the product of the output current times the voltage drop across the output pass element ( $V_{IN}$  to  $V_{OUT}$ ):

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
(4)

Power dissipation can be minimized by using the lowest possible input voltage necessary to assure the required output voltage.



# PACKAGE OPTION ADDENDUM

16-May-2005

#### **PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package<br>Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan <sup>(2)</sup>    | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|-----------------|--------------------|------|----------------|----------------------------|------------------|------------------------------|
| TPS71319DRCR     | ACTIVE                | SON             | DRC                | 10   | 3000           | Green (RoHS & no Sb/Br)    | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71319DRCRG4   | ACTIVE                | SON             | DRC                | 10   | 3000           | Green (RoHS &<br>no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71319DRCT     | ACTIVE                | SON             | DRC                | 10   | 250            | Green (RoHS & no Sb/Br)    | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71319DRCTG4   | ACTIVE                | SON             | DRC                | 10   | 250            | Green (RoHS & no Sb/Br)    | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71334DRCR     | ACTIVE                | SON             | DRC                | 10   | 3000           | Green (RoHS &<br>no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71334DRCRG4   | ACTIVE                | SON             | DRC                | 10   | 3000           | Green (RoHS & no Sb/Br)    | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71334DRCT     | ACTIVE                | SON             | DRC                | 10   | 250            | Green (RoHS &<br>no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR          |
| TPS71334DRCTG4   | ACTIVE                | SON             | DRC                | 10   | 250            | Green (RoHS &<br>no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR          |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# **MECHANICAL DATA**



- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- $\not E$  Metalized features are supplier options and may not be on the package.



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